DATA SHEET

Solid State Relay OCMOS FET

PS710A-1A, PS710AL-1A

6-PIN DIP, 0.1Ω LOW ON-STATE RESISTANCE 1.8 A CONTINUOUS LOAD CURRENT 1-ch Optical Coupled MOS FET

DESCRIPTION

NEC

The PS710A-1A and PS710AL-1A are solid state relays containing GaAs LEDs on the light emitting side (input side) and MOS FETs on the output side.

It is suitable for PLC, etc. because of its large continuous load current and low on-state resistance.

The PS710AL-1A has a surface mount type lead.

FEATURES

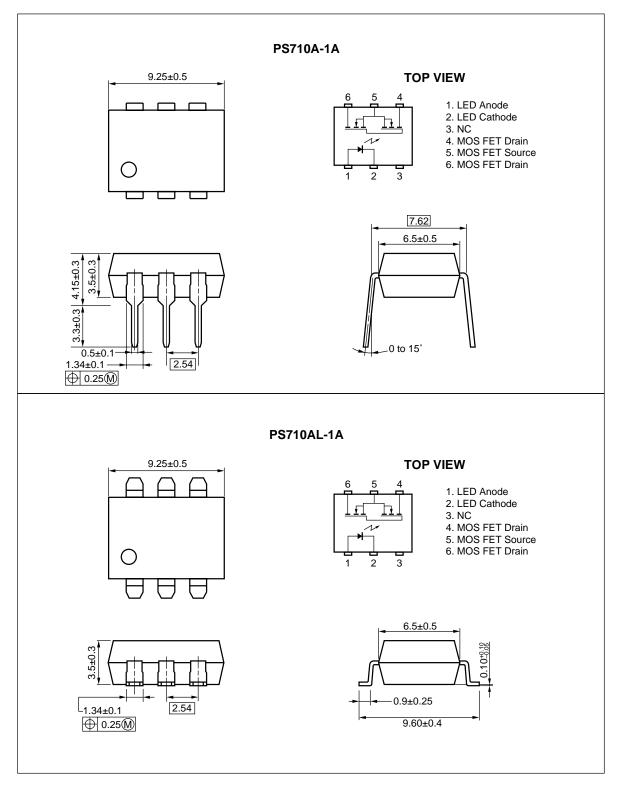
- Low on-state resistance ($R_{on} = 0.1 \Omega$ TYP.)
- Large continuous load current (IL = 1.8 A)
- 1 channel type (1 a output)
- Low LED operating current (IF = 2 mA)
- Designed for AC/DC switching line changer
- Small package (6-pin DIP)
- · Low offset voltage
- PS710AL-1A: Surface mount type

APPLICATIONS

- Measurement equipment
- FA equipment

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PACKAGE DIMENSIONS (in millimeters)



★ ORDERING INFORMATION

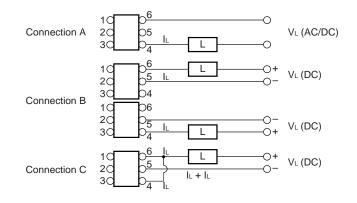
| Part Number | Package | Packing Style | Application Part Number ^{*1} |
|---------------|-----------|------------------------------|---------------------------------------|
| PS710A-1A | 6-pin DIP | Magazine case 50 pcs | PS710A-1A |
| PS710AL-1A | | | PS710AL-1A |
| PS710AL-1A-E3 | | Embossed Tape 1 000 pcs/reel | |
| PS710AL-1A-E4 | | | |

*1 For the application of the Safety Standard, following part number should be used.

| Parameter | | | Symbol | Ratings | Unit |
|--------------------------------|--|--------------|-------------|---------|------|
| Diode | Forward Current (DC) | | IF | 50 | mA |
| | Reverse Voltage | | VR | 5.0 | V |
| | Power Dissipation | | PD | 50 | mW |
| | Peak Forward Current | | IFP | 1 | А |
| MOS FET | Break Down Voltage | | VL | 60 | V |
| | Continuous | Connection A | IL. | 1.8 | А |
| | Load Current ^{*2} | Connection B | | 2.0 | |
| | | Connection C | | 3.6 | |
| | Pulse Load Current ^{'3} (AC/DC Connection) | | Ilp | 3.6 | A |
| | Power Dissipation | | P⊳ | 560 | mW |
| Isolation Voltage ⁴ | | BV | 1 500 | Vr.m.s. | |
| Total Power Dissipation | | Р⊤ | 610 | mW | |
| Operating Ambient Temperature | | TA | -40 to +85 | °C | |
| Storage Temperature | | Tstg | -40 to +100 | °C | |

*1 PW = 100 μ s, Duty Cycle = 1 %

*2 Conditions: IF \geq 2 mA. The following types of load connections are available.



*3 PW = 100 ms, 1 shot

*4 AC voltage for 1 minute at TA = 25 °C, RH = 60 % between input and output

RECOMMENDED OPERATING CONDITIONS (TA = 25 °C)

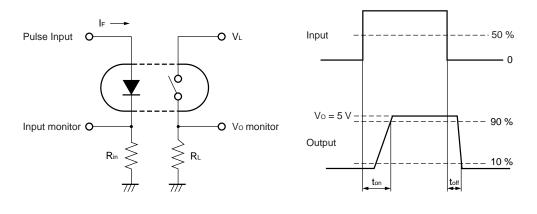
| Parameter | Symbol | Symbol MIN. | | MAX. | Unit |
|-----------------------|--------|-------------|----|------|------|
| LED Operating Current | lf | 2 | 10 | 20 | mA |
| LED Off Voltage | VF | 0 | | 0.5 | V |

ELECTRICAL CHARACTERISTICS (TA = 25 °C)

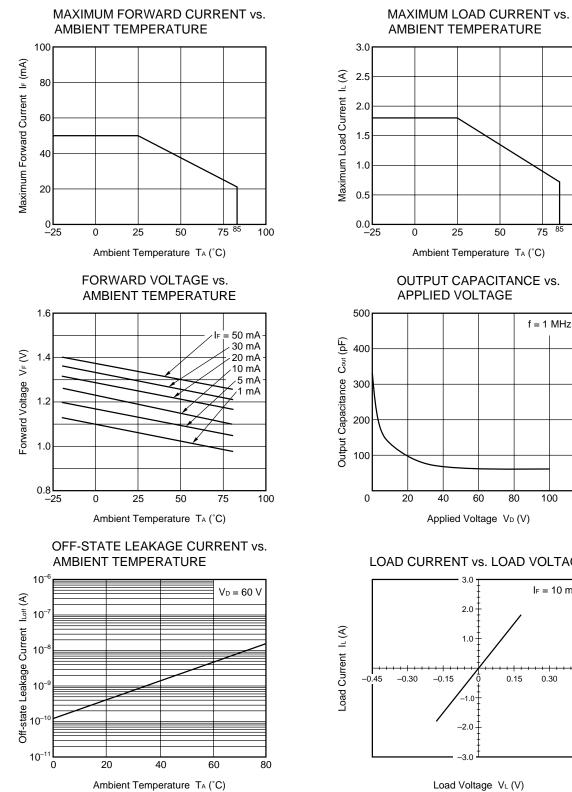
| | Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|---------|-----------------------------|--------|---|-----------------|------|------|------|
| Diode | iode Forward Voltage | | IF = 10 mA | | 1.2 | 1.4 | V |
| | Reverse Current | Ir | V _R = 5 V | | | 5.0 | μA |
| MOS FET | Off-state Leakage Current | Loff | V _D = 60 V | | | 1.0 | μA |
| | Output Capacitance | Cout | V _D = 0 V, f = 1 MHz | | 320 | | pF |
| Coupled | LED On-state Current | IFon | I∟ = 1.8 A | | | 2.0 | mA |
| | On-state Resistance | Ron | I_{F} = 10 mA, I_{L} = 1.8 A, t \leq 10 ms | | 0.1 | 0.2 | Ω |
| | Turn-on Time [™] | ton | $I_{F} = 10 \text{ mA}, \text{ Vo} = 5 \text{ V}, \text{ RL} = 500 \Omega,$ | | 1.0 | 3.0 | ms |
| | Turn-off Time ^{*1} | toff | PW ≥ 10 ms | | 0.05 | 1.0 | |
| | Isolation Resistance | Ri-o | VI-O = 1.0 kVDC | 10 [°] | | | Ω |
| | Isolation Capacitance | CI-0 | V = 0 V, f = 1 MHz | | 0.5 | | pF |

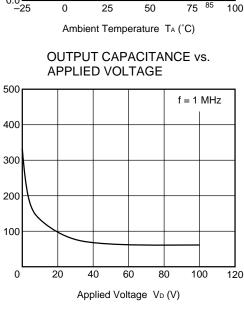
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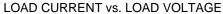
*1 Test Circuit for Switching Time

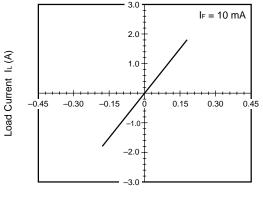


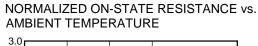
TYPICAL CHARACTERISTICS (TA = 25 °C, unless ot herwise specified) *

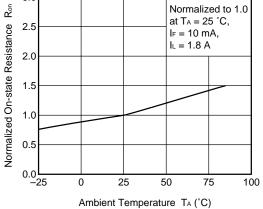




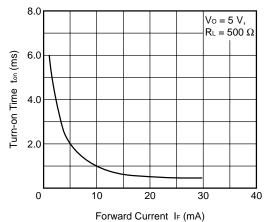




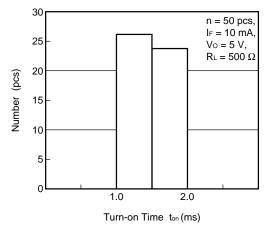




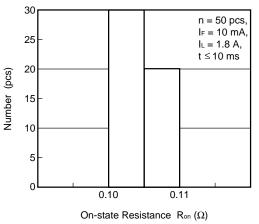
TURN-ON TIME vs. FORWARD CURRENT



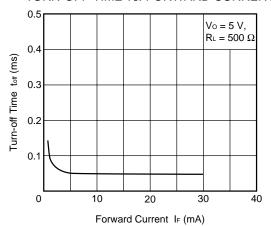
TURN-ON TIME DISTRIBUTION



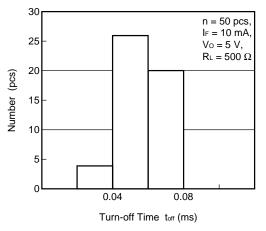
ON-STATE RESISTANCE DISTRIBUTION



TURN-OFF TIME vs. FORWARD CURRENT



TURN-OFF TIME DISTRIBUTION



Normalized to 1.0 at $T_A = 25$ °C,

75

100

I⊧ = 10 mA,

 $V_0 = 5 V,$ $R_L = 500 \Omega$

NORMALIZED TURN-OFF TIME vs.

AMBIENT TEMPERATURE

25

Ambient Temperature T_A (°C)

50

3.0

2.5

2.0

1.5

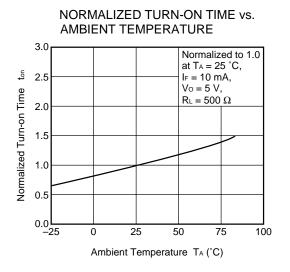
1.0

0.5

0.0

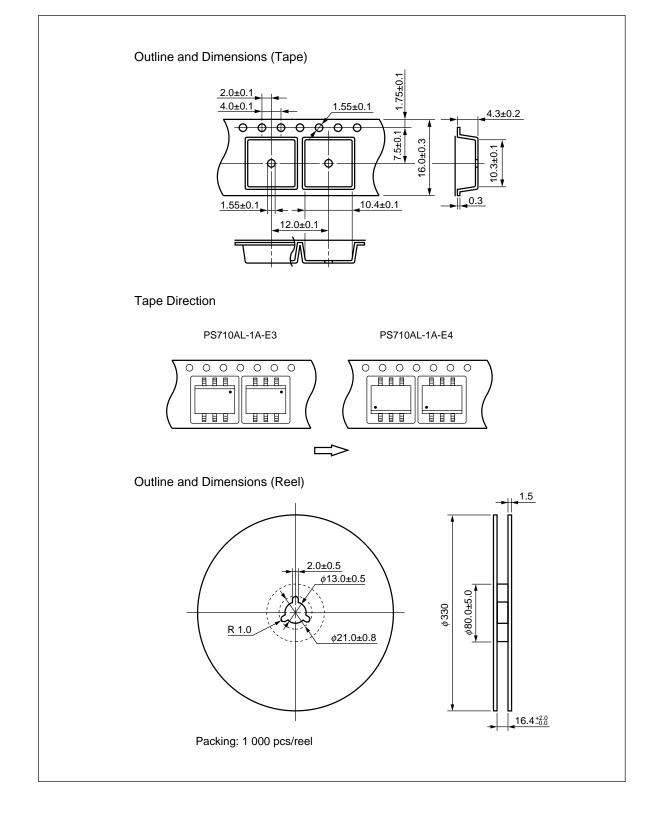
0

Normalized Turn-off Time toff



Remark The graphs indicate nominal characteristics.

***** TAPING SPECIFICATIONS (in millimeters)



★ RECOMMENDED SOLDERING CONDITIONS

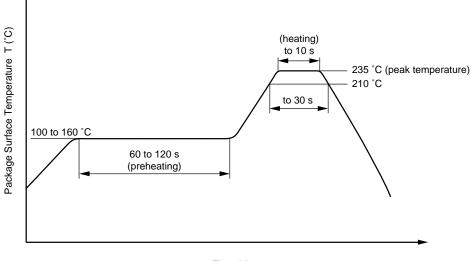
(1) Infrared reflow soldering

- Peak reflow temperature 235 °C or below (package surface temperature)
- Time of temperature higher than 210 °C
- Number of reflows
- Flux

30 seconds or less Two

Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt % is recommended.)

Recommended Temperature Profile of Infrared Reflow





(2) Dip soldering

Temperature 260 °C or below (molten solder temperature)

- Time
- 10 seconds or less
- Number of times One
- Flux

Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt % is recommended.)

(3) Cautions

Fluxes

Avoid removing the residual flux with freon-based and chlorine-based cleaning solvent.

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[MEMO]

CAUTION

Within this device there exists GaAs (Gallium Arsenide) material which is a harmful substance if ingested. Please do not under any circumstances break the hermetic seal.

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